# -3.3V / -5V Triple ECL Input to LVPECL/PECL Output Translator

The MC10/100EP90 is a TRIPLE ECL TO LVPECL/PECL translator. The device receives differential LVECL or ECL signals and translates them to differential LVPECL or PECL output signals.

A  $V_{BB}$  output is provided for interfacing with Single–Ended LVECL or ECL signals at the input. If a Single–Ended input is to be used the  $V_{BB}$  output should be connected to the  $\overline{D}$  input. The active signal would then drive the D input. When used the  $V_{BB}$  output should be bypassed to ground by a 0.01  $\mu F$  capacitor. The  $V_{BB}$  output is designed to act as the switching reference for the EP90 under Single–Ended input switching conditions, as a result this pin can only source/sink up to 0.5 mA of current.

To accomplish the level translation the EP90 requires three power rails. The  $V_{CC}$  supply should be connected to the positive supply, and the  $V_{EE}$  connected to the negative supply.

The 100 Series contains temperature compensation.

- 260 ps Typical Propagation Delay
- Maximum Frequency > 3 GHz Typical
- Voltage Supplies  $V_{CC} = 3.0 \text{ V}$  to 5.5 V,  $V_{EE} = -3.0 \text{ V}$  to -5.5 V, GND = 0 V
- Open Input Default State
- Safety Clamp on Inputs
- Fully Differential Design
- Q Output Will Default LOW with Inputs Open or at V<sub>EE</sub>
- V<sub>BB</sub> Output
- These are Pb-Free Devices\*



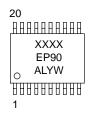
### ON Semiconductor®

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TSSOP-20 DT SUFFIX CASE 948E

#### MARKING DIAGRAM\*



xxx = MC10 or 100 A = Assembly Location L = Wafer Lot

Y = Year W = Work Week

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

<sup>\*</sup>For additional marking information, refer to Application Note AND8002/D.

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

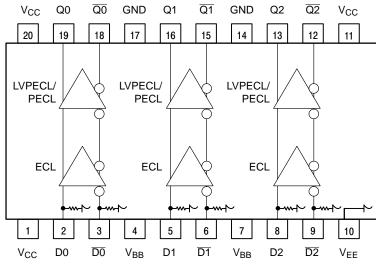


Figure 1. TSSOP-20 (Top View) and Logic Diagram

**Table 1. PIN DESCRIPTION** 

PIN	FUNCTION
Q(0:2), \( \overline{Q}(0:2)	Differential LVPECL or PECL Outputs
D(0:2)*, $\overline{D}$ (0:2)*	Differential LVECL or ECL Inputs
V <sub>CC</sub>	Positive Supply
GND	Ground
V <sub>EE</sub>	Negative Supply
$V_{BB}$	Output Reference Supply

<sup>\*</sup> Pins will default LOW when left open.

### **Table 2. FUNCTION TABLE**

Function	V <sub>CC</sub>	GND	V <sub>EE</sub>
-5V ECL to 5V PECL	5 V	0 V	–5 V
-5V ECL to 3.3V PECL	3.3 V	0 V	–5 V
-3.3V ECL to 5V PECL	5 V	0 V	-3.3 V
-3.3V ECL to 3.3V PECL	3.3 V	0 V	-3.3 V

**Table 3. ATTRIBUTES** 

Characteris	tics	Value
Internal Input Pulldown Resistor		75 kΩ
Internal Input Pullup Resistor	N/A	
ESD Protection	Human Body Model Machine Model Charged Device Model	> 2 kV > 200 V > 2 kV
Moisture Sensitivity, Indefinite Time	Out of Drypack (Note 1)	Level 1
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in
Transistor Count	350 Devices	
Meets or exceeds JEDEC Spec EIA	/JESD78 IC Latchup Test	

<sup>1.</sup> For additional information, refer to Application Note AND8003/D.

**Table 4. MAXIMUM RATINGS** 

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V <sub>CC</sub>	PECL Mode Power Supply	GND = 0 V		6	V
V <sub>EE</sub>	NECL Mode Power Supply	GND = 0 V		-6	V
VI	PECL Mode Input Voltage NECL Mode Input Voltage	GND = 0 V GND = 0 V	$\begin{aligned} & V_{I} \leq V_{CC} \\ & V_{I} \geq V_{EE} \end{aligned}$	6 -6	V V
l <sub>out</sub>	Output Current	Continuous Surge		50 100	mA mA
I <sub>BB</sub>	V <sub>BB</sub> Sink/Source			± 0.5	mA
T <sub>A</sub>	Operating Temperature Range			-40 to +85	°C
T <sub>stg</sub>	Storage Temperature Range			-65 to +150	°C
θ <sub>JA</sub>	Thermal Resistance (Junction–to–Ambient)	0 lfpm 500 lfpm	TSSOP-20 TSSOP-20	140 100	°C/W
$\theta_{\sf JC}$	Thermal Resistance (Junction-to-Case)	Standard Board	TSSOP-20	23 to 41	°C/W
T <sub>sol</sub>	Wave Solder	<2 to 3 sec @ 248°C		265	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

Table 5. 10EP DC CHARACTERISTICS  $V_{CC} = 3.3 \text{ V}$ ,  $V_{EE} = -5.5 \text{ V}$  to -3.0 V; GND = 0 V (Note 2)

			-40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Negative Power Supply Current	5	13	20	5	13	20	5	13	20	mA
Icc	Positive Power Supply Current	43	55	67	43	55	67	43	55	67	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 3)	2165	2290	2415	2230	2355	2480	2290	2415	2540	mV
V <sub>OL</sub>	Output LOW Voltage (Note 3)	1365	1490	1615	1430	1555	1680	1490	1615	1740	mV
V <sub>IH</sub>	Input HIGH Voltage (Single-Ended)	-1210		-885	-1145		-820	-1085		-760	mV
V <sub>IL</sub>	Input LOW Voltage (Single-Ended)	-1935		-1610	-1870		-1545	-1810		-1485	mV
V <sub>BB</sub>	Output Voltage Reference	-1510	-1410	-1310	-1445	-1345	-1245	-1385	-1285	-1185	mV
V <sub>IHCMR</sub>	Input HIGH Voltage Common Mode Range (Differential) (Note 4)	V <sub>EE</sub>	+2.0	0.0	V <sub>EE</sub>	+2.0	0.0	V <sub>EE</sub>	+2.0	0.0	V
I <sub>IH</sub>	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 2. Input and output parameters vary 1:1 with  $V_{CC}$ .
- 3. All loading with 50  $\Omega$  to  $V_{CC}$  2.0 V. 4.  $V_{IHCMR}$  min varies 1:1 with  $V_{EE}$ , max varies 1:1 with  $V_{CC}$ . The  $V_{IHCMR}$  range is referenced to the most positive side of the differential input

Table 6. 10EP DC CHARACTERISTICS  $V_{CC} = 5.0 \text{ V}$ ,  $V_{EE} = -5.5 \text{ V}$  to -3.0 V; GND = 0 V (Note 5)

			-40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Negative Power Supply Current	5	13	20	5	13	20	5	13	20	mA
I <sub>CC</sub>	Positive Power Supply Current	43	55	67	43	55	67	43	55	67	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 6)	3865	3990	4115	3930	4055	4180	3990	4115	4240	mV
V <sub>OL</sub>	Output LOW Voltage (Note 6)	3065	3190	3315	3130	3255	3380	3190	3315	3440	mV
V <sub>IH</sub>	Input HIGH Voltage (Single-Ended)	-1210		-885	-1145		-820	-1085		-760	mV
$V_{IL}$	Input LOW Voltage (Single-Ended)	-1935		-1610	-1870		-1545	-1810		-1485	mV
V <sub>BB</sub>	Output Voltage Reference	-1510	-1410	-1310	-1445	-1345	-1245	-1385	-1285	-1185	mV
V <sub>IHCMR</sub>	Input HIGH Voltage Common Mode Range (Differential) (Note 7)	V <sub>EE</sub>	+2.0	0.0	V <sub>EE</sub>	+2.0	0.0	V <sub>EE</sub>	+2.0	0.0	V
I <sub>IH</sub>	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 5. Input and output parameters vary 1:1 with V<sub>CC</sub>.
- 6. All loading with 50  $\Omega$  to  $V_{CC}$  2.0 V.
- 7. VIHCMR min varies 1:1 with VEE, max varies 1:1 with VCC. The VIHCMR range is referenced to the most positive side of the differential input

100EP DC CHARACTERISTICS  $V_{CC} = 3.3 \text{ V}$ ,  $V_{EE} = -5.5 \text{ V}$  to -3.0 V; GND = 0 V (Note 8)

			-40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Negative Power Supply Current	5	13	20	5	13	20	5	13	20	mA
Icc	Positive Power Supply Current	45	58	70	50	62	75	53	65	78	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 9)	2155	2280	2405	2155	2280	2405	2155	2280	2405	mV
V <sub>OL</sub>	Output LOW Voltage (Note 9)	1355	1480	1605	1355	1480	1605	1355	1480	1605	mV
V <sub>IH</sub>	Input HIGH Voltage (Single-Ended)	-1210		-885	-1145		-820	-1085		-760	mV
V <sub>IL</sub>	Input LOW Voltage (Single-Ended)	-1935		-1610	-1870		-1545	-1810		-1485	mV
V <sub>BB</sub>	Output Voltage Reference	-1525	-1425	-1325	-1525	-1425	-1325	-1525	-1425	-1325	mV
V <sub>IHCMR</sub>	Input HIGH Voltage Common Mode Range (Differential) (Note 10)	V <sub>EE</sub>	+2.0	0.0	V <sub>EE</sub> -	+2.0	0.0	V <sub>EE</sub>	+2.0	0.0	V
I <sub>IH</sub>	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 8. Input and output parameters vary 1:1 with V<sub>CC</sub>.

### **100EP DC CHARACTERISTICS** $V_{CC} = 5.0 \text{ V}, V_{EE} = -5.5 \text{ V}$ to -3.0 V; GND = 0 V (Note 11)

			-40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>EE</sub>	Negative Power Supply Current	5	13	20	5	13	20	5	13	20	mA
I <sub>CC</sub>	Positive Power Supply Current	45	58	70	50	62	75	53	65	78	mA
$V_{OH}$	Output HIGH Voltage (Note 12)	3855	3980	4105	3855	3980	4105	3855	3980	4105	mV
V <sub>OL</sub>	Output LOW Voltage (Note 12)	3055	3180	3305	3055	3180	3305	3055	3180	3305	mV
V <sub>IH</sub>	Input HIGH Voltage (Single-Ended)	-1210		-885	-1145		-820	-1085		-760	mV
V <sub>IL</sub>	Input LOW Voltage (Single-Ended)	-1935		-1610	-1870		-1545	-1810		-1485	mV
$V_{BB}$	Output Voltage Reference	-1525	-1425	-1325	-1525	-1425	-1325	-1525	-1425	-1325	mV
V <sub>IHCMR</sub>	Input HIGH Voltage Common Mode Range (Differential) (Note 13)	V <sub>EE</sub>	+2.0	0.0	V <sub>EE</sub>	+2.0	0.0	V <sub>EE</sub>	+2.0	0.0	V
I <sub>IH</sub>	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 11. Input and output parameters vary 1:1 with  $V_{CC}$ .
- 12. All loading with 50  $\Omega$  to  $V_{CC}$  2.0 V. 13.  $V_{IHCMR}$  min varies 1:1 with  $V_{EE}$ , max varies 1:1 with  $V_{CC}$ .. The  $V_{IHCMR}$  range is referenced to the most positive side of the differential input

<sup>9.</sup> All loading with  $50 \Omega$  to  $V_{CC} - 2.0 \text{ V}$ . 10.  $V_{IHCMR}$  min varies 1:1 with  $V_{EE}$ , max varies 1:1 with  $V_{CC}$ . The  $V_{IHCMR}$  range is referenced to the most positive side of the differential input signal.

Table 7. AC CHARACTERISTICS  $V_{EE} = -3.0 \text{ V}$  to -5.5 V;  $V_{CC} = 3.0 \text{ V}$  to 5.5 V; GND = 0 V (Note 14)

			-40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f <sub>max</sub>	Maximum Frequency (See Figure 2 F <sub>max</sub> /JITTER)		> 3			> 3			> 3		GHz
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay to Output Differential	170	240	310	200	260	340	230	300	370	ps
t <sub>SKEW</sub>	Duty Cycle Skew (Note 15)		5.0	20		5.0	20		5.0	20	ps
	Within Device Skew Q, Q Device to Device Skew (Note 15)			80 140			80 140			80 140	
t <sub>JITTER</sub>	Cycle-to-Cycle Jitter (See Figure 2 F <sub>max</sub> /JITTER)		0.2	< 1		0.2	< 1		0.2	< 1	ps
V <sub>PP</sub>	Input Voltage Swing (Differential Configuration)	150	800	1200	150	800	1200	150	800	1200	mV
t <sub>r</sub> t <sub>f</sub>	Output Rise/Fall Times Q, $\overline{\mathbb{Q}}$ (20% – 80%)	70	120	170	80	130	180	100	150	230	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

14. Measured using a 750 mV source, 50% duty cycle clock source. All loading with 50  $\Omega$  to V<sub>CC</sub>-2.0 V.

<sup>15.</sup> Skew is measured between outputs under identical transitions. Duty cycle skew is defined only for differential operation when the delays are measured from the cross point of the inputs to the cross point of the outputs.

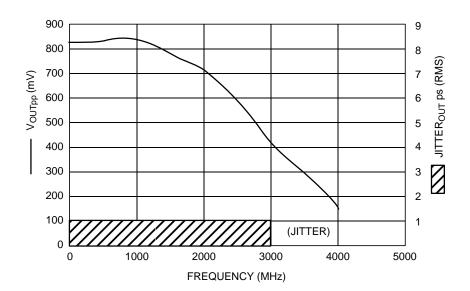


Figure 2. F<sub>max</sub>/Jitter

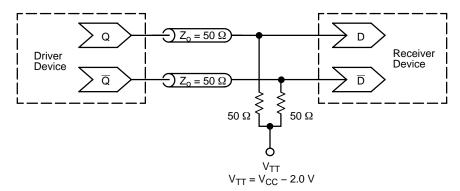


Figure 3. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020/D – Termination of ECL Logic Devices.)

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>				
MC10EP90DT	TSSOP-20	75 Units / Rail				
MC10EP90DTR2	TSSOP-20	2500 / Tape & Rail				
MC100EP90DT	TSSOP-20	75 Units / Rail				
MC100EP90DTR2	TSSOP-20	2500 / Tape & Rail				

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### **Resource Reference of Application Notes**

AN1405/D - ECL Clock Distribution Techniques

AN1406/D - Designing with PECL (ECL at +5.0 V)

AN1503/D - ECLinPS™ I/O SPiCE Modeling Kit

AN1504/D - Metastability and the ECLinPS Family

AN1568/D - Interfacing Between LVDS and ECL

AN1642/D - The ECL Translator Guide

AND8001/D - Odd Number Counters Design

AND8002/D - Marking and Date Codes

AND8020/D - Termination of ECL Logic Devices

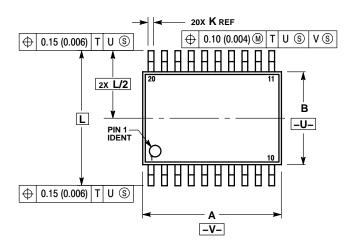
AND8066/D - Interfacing with ECLinPS

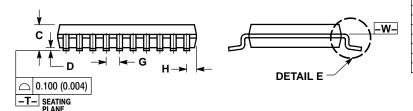
AND8090/D - AC Characteristics of ECL Devices

### PACKAGE DIMENSIONS

### TSSOP-20 **DT SUFFIX**

PLASTIC TSSOP PACKAGE CASE 948E-02 **ISSUE B** 





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
   CONTROLLING DIMENSION:
- MILLIMETER.
- DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER
- DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION.
  INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE
- DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL
- CONDITION.
  TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.
  DIMENSION A AND B ARE TO BE
  DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS INCHES									
	MILLIN	IETERS	INC	HES						
DIM	MIN	MAX	MIN	MAX						
Α	6.40	6.60	0.252	0.260						
В	4.30	4.50	0.169	0.177						
С		1.20		0.047						
D	0.05	0.15	0.002	0.006						
F	0.50	0.75	0.020	0.030						
G	0.65	BSC	0.026 BSC							
Н	0.27	0.37	0.011	0.015						
J	0.09	0.20	0.004	0.008						
J1	0.09	0.16	0.004	0.006						
K	0.19	0.30	0.007	0.012						
K1	0.19	0.25	0.007	0.010						
L	6.40	BSC	0.252 BSC							
M	0°	8°	0°	8°						

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